SMC SANGDEST MICROELECTRONICS

SDUR2020CT

Technical Data Data Sheet N0374, Rev. - **Green Products** 

# SDUR2020CT ULTRAFAST PLASTIC RECTIFIER

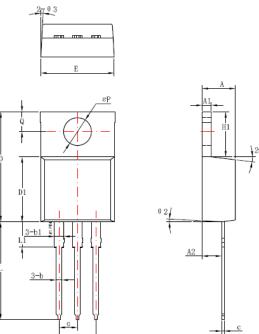
#### **Applications:**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

#### Features:

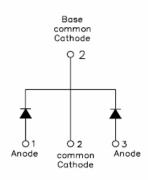
- Utra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request





	Dimensions in millimeters			
Symbol	Min	Typical	Max	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1		5.06		
H1	6.04	6.24	6.44	
L	12.7	13.56	13.78	
L1		3.5		
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		<b>4</b> °		

### **TO-220AB**



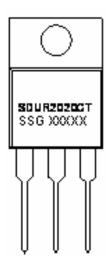


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### Marking Diagram:



Where XXXXX is YYWWL

SDUR	= Device Type
20	= Forward Current (20A)
20	= Reverse Voltage (200V)
СТ	= Configuration
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping	
SDUR2020CT	TO-220AB	EQnos (tubo	
	(Pb-Free)	50pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	200	V
Average Rectified Forward Current (total device)	I <sub>F (AV)</sub>	Rated Vr ,@Tc=105°C	20	А
Max. Peak One Cycle Non- Repetitive Surge Current (Per leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	120	A

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage	V <sub>F1</sub>	@ 10A, Pulse, T <sub>J</sub> = 25°C	1.05	V
Drop(Per leg)*	V <sub>F2</sub>	@ 10A, Pulse, T <sub>J</sub> = 125°C	0.85	V
	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub>	10	μA
Max. Reverse Current*		$T_J = 25^{\circ}C$		
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub>	500	uA
		T <sub>J</sub> = 150°C		
Max. Reverse Recovery Time	t <sub>rr</sub>	$I_F$ =500mA, $I_R$ =1A,and $I_{rm}$ =250mA	35	ns

\* Pulse width < 300  $\mu s, \ duty \ cycle < 2\%$ 

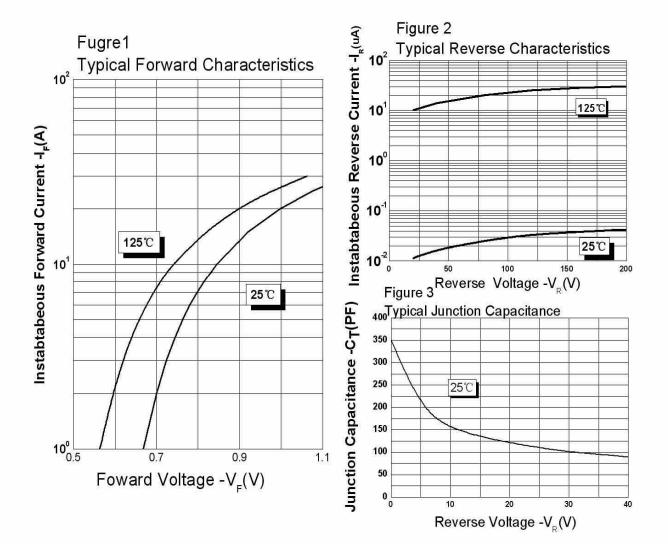
## Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal	R <sub>0JC</sub>	DC operation	1.6	°C/W
Resistance Junction to Case				
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			



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